



DOCUMENT CHANGE REQUEST

DCR number		1653		Changes required for: General		Originator: Stephan Hernandez	
Date: 2024/04/08				Date sent: 2024/04/08		Organisation: ESTEC	
Status: IMPLEMENTED							
Title:	REP005						
Number:	REP005		Issue:	247			
Other documents affected:							
Page:							
-							
Paragraph:							
-							
Original wording:							
-							
Proposed wording:							
New: 388, United Monolithic Semiconductors (France) Transistors, Microwave, GaN HEMT, in metal Ceramic Package, based on the UMS GH50-20 GaN HEMT power bar technology (Technology Flow Qualified).							
Justification:							
Publication QPL March 2024							
Attachments:							
N/A							
Modifications:							
N/A							
Approval signature:							
Date signed:							
2024-04-08							